

COMPLIANT

## Precision Low-Voltage, Low-Glitch CMOS Analog Switches

### **DESCRIPTION**

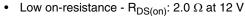
Using BiCMOS wafer fabrication technology allows the DG9421, DG9422 to operate on single and dual supplies.

Designed for optimal performance at single 5 V and dual  $\pm$  5 V, the DG9421, DG9422 combine low and flat on-resistance (3  $\Omega$ ), fast speed ( $t_{ON}$  = 38 ns) and is well suited for applications where signal switching accuracy, low noise and low distortion is critical.

The DG9421 and DG9422 respond to opposite control logic as shown in the Truth Table.

### **FEATURES**

 2.7- thru 12 V single supply or ± 2.7- thru ± 6-dual supply



Fast switching - t<sub>ON</sub>: 28 ns

- t<sub>OFF</sub>: 22 ns

TTL and low voltage logic

Low leakage: 10 pA (typ.)

• > 2000 V ESD protection

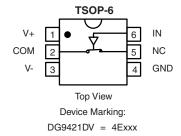
### **BENEFITS**

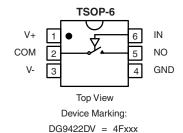
- High accuracy
- · High speed, low glitch
- · Single and dual supply capability
- Low R<sub>ON</sub> in small TSOP package
- Low leakage
- · Low power consumption

### **APPLICATIONS**

- · Automatic test equipment
- · Data acquisition
- · XDSL and DSLAM
- · PBX systems
- · Reed relay replacement
- · Audio and video signal routing

### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**





TRUTH TABLE					
Logic	DG9421	DG9422			
0	ON	OFF			
1	OFF	ON			

Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

Switches Shown for Logic "0" Input

ORDERING INFORMATION					
Temp. Range	Package	Part Number			
- 40 °C to 85 °C	6/Din TSOD	DG9421DV-T1 DG9421DV-T1-E3			
	6/Pin TSOP	DG9422DV-T1 DG9422DV-T1-E3			

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

Document Number: 70679 S-82265-Rev. F, 29-Sep-08



ABSOLUTE MAXIMUM RATINGS							
Parameter		Limit	Unit				
V+ to V-		- 0.3 to 13	V				
GND to V-		7	]				
$V_{IN}{}^a, V_S, V_D$		- 0.3 to (V+ + 0.3) or 50 mA, whichever occurs first	V/mA				
Continuous Current (Any Terminal)		50	mA				
Peak Current, S or D (Pulsed at 1 ms, 1	0 % Duty Cycle)	100	IIIA				
Storage Temperature		- 65 to 150	°C				
Power Dissipation (Packages) <sup>b</sup> 6-Pin TSOP <sup>c</sup>		570	mW				

### Notes:

- a. Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC board.
- c. Derate 7 mW/°C above 25 °C.

		Test Conditions Unless Otherwise Specified		Limits - 40 °C to 85°C			
Parameter	Symbol	$V+ = 12 V$ , $V- = 0 V$ , $V_{IN} = 2.4 V$ , $0.8 V^f$	Temp.b	Min.d	Typ.c	Max. <sup>d</sup>	Unit
Analog Switch							
Analog Signal Range <sup>a</sup>	V <sub>ANALOG</sub>		Full	0		12	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	$V+ = 10.8 \text{ V}, V- = 0 \text{ V}, I_S = 5 \text{ mA}, V_D = 2/9 \text{ V}$	Room Full		2.0	3 3.4	Ω
Switch Off	I <sub>S(off)</sub>	V <sub>D</sub> = 1/11 V, V <sub>S</sub> = 11/1 V	Room Full	- 1 - 10		1 10	
Leakage Current	I <sub>D(off)</sub>	v <sub>D</sub> - 1/11 v, v <sub>S</sub> - 11/1 v	Room Full	- 1 - 10		1 10	nA
Channel-On Leakage Current	I <sub>D(on)</sub>	$V_S = V_D = 11/1 V$	Room Full	- 1 - 10		1 10	
Digital Control							
Input Current, V <sub>IN</sub> Low	I <sub>IL</sub>	V <sub>IN</sub> Under Test = 0.8 V	Full	- 1	0.02	1	μΑ
Input Current, V <sub>IN</sub> High	I <sub>IH</sub>	V <sub>IN</sub> Under Test = 2.4 V	Full	- 1	0.02	1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	t <sub>ON</sub>	$R_L = 300 \ \Omega, \ C_L = 35 \ pF, \ V_S = 5 \ V$	Room Full		20	45 49	no
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	See Figure 2	Room Full		25	47 59	ns
Charge Injection <sup>e</sup>	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room		43		рС
Off-Isolation <sup>e</sup>	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room		- 60		dB
Source Off Capacitance <sup>e</sup>	C <sub>S(off)</sub>		Room		31		
Drain Off Capacitance <sup>e</sup>	C <sub>D(off)</sub>	f = 1 MHz	Room		30		pF
Channel On Capacitance <sup>e</sup>	C <sub>D(on)</sub>		Room		71		
Power Supplies					•		
Positive Supply Current	l+		Room Full		0.02	1 5	
Negative Supply Current	I-	V <sub>IN</sub> = 0 or 12 V	Room Full	- 1 - 5	- 0.002		μΑ
Ground Current	I <sub>GND</sub>		Room Full	- 1 - 5	- 0.002		



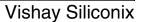
		Test Conditions Unless Otherwise Specified		- 40	Limits 0 °C to 85	°C	
Parameter	Symbol	$V+ = 5 V$ , $V- = -5 V$ , $V_{IN} = 2.4 V$ , $0.8 V^f$	Temp.b	Min. <sup>d</sup>	Typ. <sup>c</sup>	Max. <sup>d</sup>	Uni
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	- 5		5	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V+ = 5 V, V- = -5 V $I_S = 5 mA, V_D = \pm 3.5 V$	Room Full		2.2	3.2 3.6	Ω
Switch Off	I <sub>S(off)</sub>	V+ = 5.5 V, V- = - 5.5 V	Room Full	- 1 - 10		1 10	
Leakage Current <sup>g</sup>	I <sub>D(off)</sub>	$V_D = \pm 4.5 \text{ V}, V_S = -/+ 4.5 \text{ V}$	Room Full	- 1 - 10		1 10	nA
Channel-On Leakage Current <sup>g</sup>	I <sub>D(on)</sub>	V+ = 5.5 V, V- = -5.5 V $V_S = V_D = \pm 4.5 V$	Room Full	- 1 - 10		1 10	
Digital Control							
Input Current, V <sub>IN</sub> Low <sup>e</sup>	I <sub>IL</sub>	V <sub>IN</sub> Under Test = 0.8 V	Full	- 1	0.02	1	
Input Current, V <sub>IN</sub> High <sup>e</sup>	I <sub>IH</sub>	V <sub>IN</sub> Under Test = 2.4 V	Full	- 1	0.02	1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	$R_L = 300 \ \Omega, \ C_L = 35 \ pF, \ V_S = \pm 3.5 \ V$	Room Full		38	63 68	ne
Turn-Off Time	t <sub>OFF</sub>	See Figure 2	Room Full		45	83 97	ns
Charge Injection <sup>e</sup>	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room		207		рС
Off-Isolation <sup>e</sup>	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room		- 57		dB
Source Off Capacitance <sup>e</sup>	C <sub>S(off)</sub>		Room		32		
Drain Off Capacitance <sup>e</sup>	C <sub>D(off)</sub>	f = 1 MHz	Room		31		pF
Channel On Capacitance <sup>e</sup>	C <sub>D(on)</sub>		Room		71		
Power Supplies							
Positive Supply Current <sup>e</sup>	l+	V <sub>IN</sub> = 0 or 5 V	Room Full		0.03	1 5	
Negative Supply Current <sup>e</sup>	I-		Room Full	- 1 - 5	- 0.002		μΑ
Ground Current <sup>e</sup>	I <sub>GND</sub>		Room Full	- 1 - 5	- 0.002		

## DG9421, DG9422

## Vishay Siliconix



SPECIFICATIONS <sup>a</sup>	Single Supp	oly 5 V					
		Test Conditions Unless Otherwise Specified		Limits - 40 °C to 85 °C		°C	
Parameter	Symbol	$V+ = 5 V$ , $V- = 0 V$ , $V_{1N} = 2.4 V$ , $0.8 V^f$	Temp.b	Min. <sup>d</sup>	Typ. <sup>c</sup>	Max.d	Unit
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0		5	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	$V+ = 4.5 \text{ V}, I_S = 5 \text{ mA},$ $V_D = 1 \text{ V}, 3.5 \text{ V}$	Room Full		3.6	6.0 6.6	Ω
Dynamic Characteristics			•				
Turn-On Time <sup>e</sup>	t <sub>ON</sub>	$R_1 = 300 \Omega$ , $C_1 = 35 pF$ , $V_S = 3.5 V$ ,	Room Hot		43	67 74	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	See Figure 2	Room Hot		30	67 80	ns
Charge Injection <sup>e</sup>	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room		25		рC
Power Supplies							
Positive Supply Current <sup>e</sup>	l+		Room Hot		0.02	1 5	
Negative Supply Current <sup>e</sup>	I-	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Hot	- 1 - 5	- 0.002		μΑ
Ground Current <sup>e</sup>	I <sub>GND</sub>		Room Hot	- 1 - 5	- 0.002		





SPECIFICATIONS <sup>a</sup>	Single Supply	' 3 V					
		Test Conditions Unless Otherwise Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	$V+ = 3 V, V- = 0 V, V_{1N} = 0.4 V^{f}$	Temp <sup>b</sup>	Min. <sup>d</sup>	Typ.c	Max. <sup>d</sup>	Unit
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0		3	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V+ = 2.7  V, V- = 0  V $I_S = 5 \text{ mA}, V_D = 0.5, 2.2 \text{ V}$	Room Full		7.3	8.8 10.1	Ω
Switch Off	I <sub>S(off)</sub>	V+ = 3.3 V, V- = 0 V	Room Full	- 1 - 10		1 10	
Leakage Current <sup>g</sup>	I <sub>D(off)</sub>	$V_S = 1, 2 V, V_D = 2, 1 V$	Room Full	- 1 - 10		1 10	nA
Channel-On Leakage Current <sup>g</sup>	I <sub>D(on)</sub>	V+ = 3.3  V, V- = 0  V $V_D = V_S = 1, 2 \text{ V}$	Room Full	- 1 - 10		1 10	
Digital Control	1		<b>,</b>	ı	II.	•	<u>I</u>
Input Current, V <sub>IN</sub> Low <sup>e</sup>	I <sub>IL</sub>	$V_{IN}$ Under Test = 0.4 V	Full	- 1	0.02	1	
Input Current, V <sub>IN</sub> High <sup>e</sup>	I <sub>IH</sub>	V <sub>IN</sub> Under Test = 2.4 V	Full	- 1	0.02	1	μΑ
Dynamic Characteristics						•	
Turn-On Time	t <sub>ON</sub>	$R_L = 300 \Omega$ , $C_L = 35 pF$ , $V_S = 1.5 V$	Room Full		90	110 125	ns
Turn-Off Time	t <sub>OFF</sub>	See Figure 2	Room Full		32	84 99	113
Charge Injection <sup>e</sup>	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room		31		рС
Off-Isolation <sup>e</sup>	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room		- 60		dB
Source Off Capacitance <sup>e</sup>	C <sub>S(off)</sub>	f = 1 MHz	Room		35		
Drain Off Capacitance <sup>e</sup>	C <sub>D(off)</sub>		Room		34		pF
Channel On Capacitance <sup>e</sup>	C <sub>D(on)</sub>		Room		77		

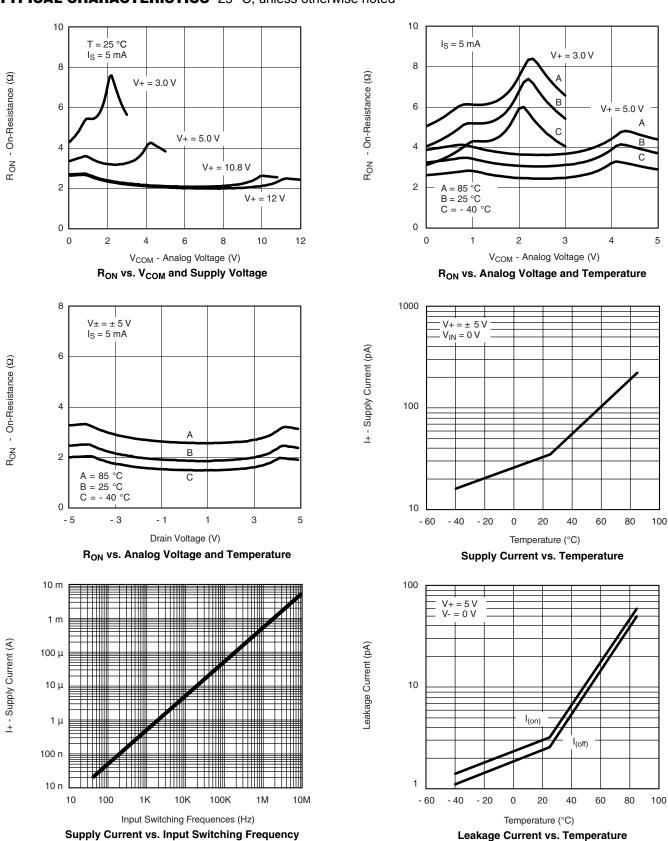
#### Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25  $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = input voltage to perform proper function.
- g. Leakage parameters are guaranteed by worst case test conditions and not subject to test.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

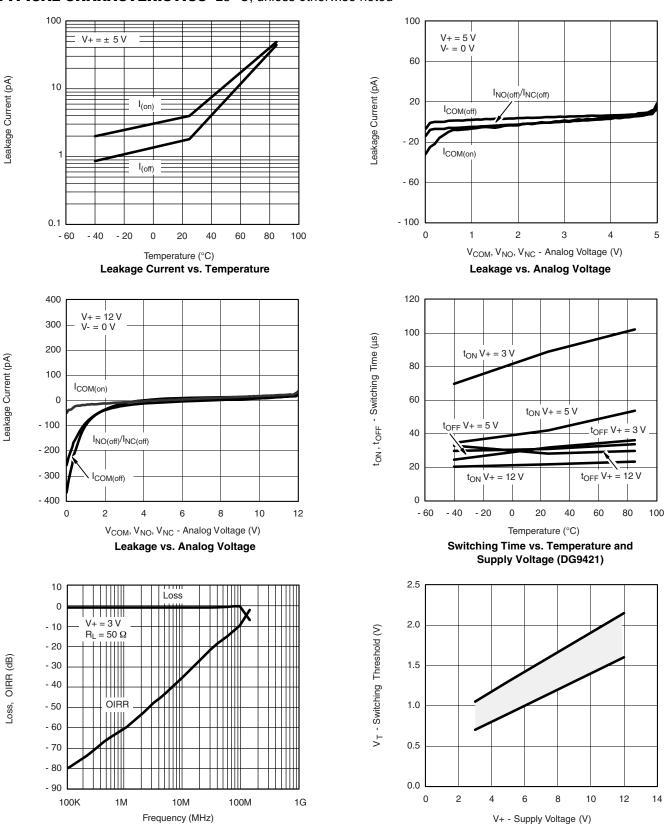
## VISHAY.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



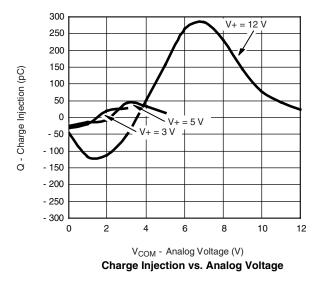
Document Number: 70679 S-82265-Rev. F, 29-Sep-08

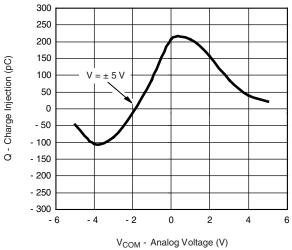
Insertion Loss, Off Isolation vs. Frequency

Switching Threshold vs. Supply Voltage

# VISHAY.

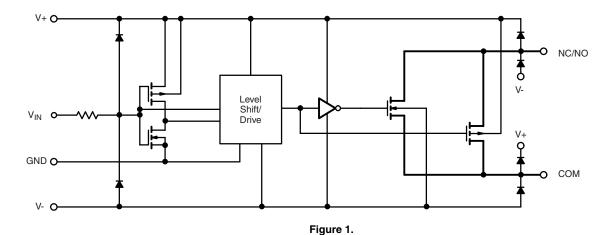
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



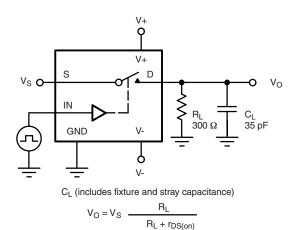


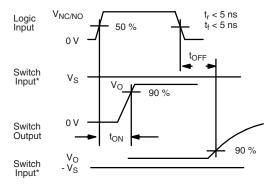
Charge Injection vs. Analog Voltage

### **SCHEMATIC DIAGRAM** Typical Channel



### **TEST CIRCUITS**



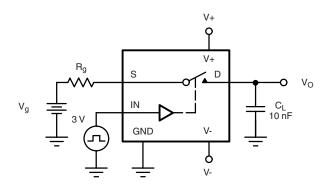


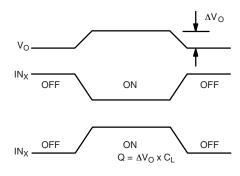
Note: \* Logic input waveform is inverted for switches that have the opposite logic sense control

Figure 2. Switching Time



### **TEST CIRCUITS**





 $\ensuremath{\mathsf{IN}}_X$  dependent on switch configuration Input polarity determined by sense of switch.

Figure 3. Charge Injection

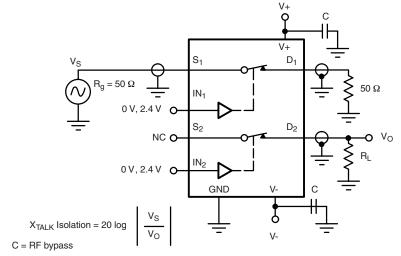
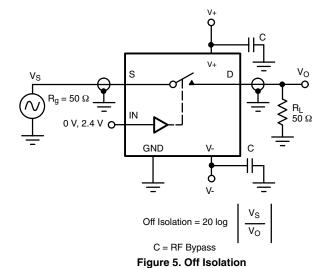


Figure 4. Crosstalk



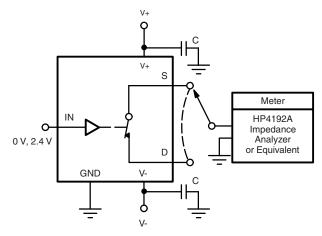


Figure 6. Source/Drain Capacitances

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?70679">http://www.vishay.com/ppg?70679</a>.

Document Number: 70679 S-82265-Rev. F, 29-Sep-08

### **Legal Disclaimer Notice**



Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1